

DESCRIPTION:

The X0202MA SCR provides high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on residual current circuit breaker, straight hair, igniter etc.

TO-126 TO-251

TO-92

MAIN FEATURES

Symbol	Value	Unit
I _{T(RMS)}	2	А
I _{GT}	≤200	μA

ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	$^{\circ}$ C
Operating junction temperature range		Tj	-40-125 ^①	$^{\circ}$ C
Repetitive peak off-state voltage		V _{DRM}	600	V
Repetitive peak reverse voltage		V _{RRM}	600	V
	TO-92 (T _C =95℃)		2	А
RMS on-state current	TO-126/	I _{T(RMS)}		
	TO-251(T _C =105°C)			
Non repetitive surge peak on-state current (F=50Hz tp=10ms)		Ітѕм	20	А
Non repetitive surge peak on-state current (F=60Hz tp=8.3ms)		Ітѕм	22	А
I ² t value for fusing (tp=10ms)		l ² t	2	A ² s
Critical rate of rise of on-state current		dI/dt	50	A/µs
Peak gate current (tp=20µs, T _j =125℃)		I _{GM}	0.2	Α
Peak gate power (tp=20µs, T _j =125℃)		P _{GM}	0.5	W
Average gate power dissipation(T _j =125°C)		P _{G(AV)}	0.1	W

NOTE 1: When we parallel connect a $\leq 1K\Omega$ resistor between Gate and Cathode, the Tj can reach 125° C; if without this resistor, the Tj only can reach 110° C.



ELECTRICAL CHARACTERISTICS (T_j =25 $^{\circ}$ C unless otherwise specified)

Symbol	Test Condition	Value			llnit
Symbol		MIN.	TYP.	MAX.	Unit
Іст	V _D =12V R _L =33Ω	ı	50	200	μA
V _G T	VD-12V NL-3322	ı	0.6	0.8	V
V _{GD}	V _D =V _{DRM} T _j =125℃	0.2	1	-	V
IL	I _G =1.2 I _{GT}	1	1	6	mA
Ін	I _T =0.05A	1	1	5	mA
dV/dt	V _D =400V T _j =125℃ R _{GK} =1KΩ	60	-	-	\//uo
	V _D =400V T _j =125℃ R _{GK} =220Ω	500	-	-	V/µs
R _d	Dynamic Resistance Tj=125℃	-	-	180	mΩ

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V _{TM}	I _T =4A tp=380μs	T _j =25℃	1.5	V
IDRM	VD=VDRM VR=VRRM	T _j =25℃	5	μA
I _{RRM}		T _j =125℃	100	μA

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
Rth(j-c)	junction to case	TO-92	10	°C/W
		TO-126	7.0	
		TO-251	6.5	



FIG.1: Maximum power dissipation versus RMS on-state current

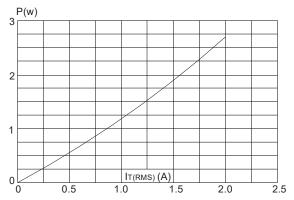


FIG.3: Surge peak on-state current versus number of cycles

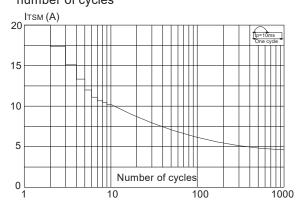


FIG.2: RMS on-state current versus case temperature

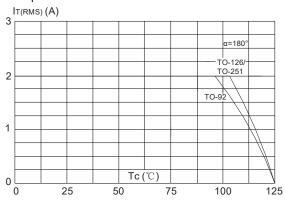


FIG.4: On-state characteristics (maximum values)

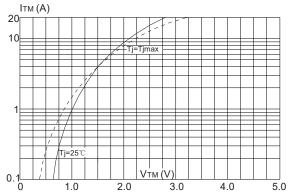




FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms, and corresponging value of I^2t (dI/dt < 50A/ μ s)

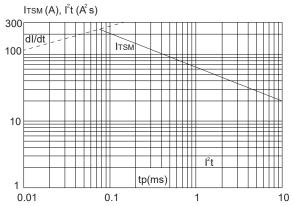


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

